

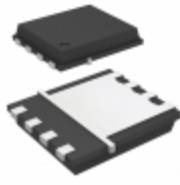
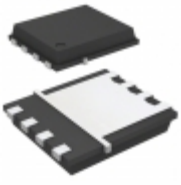
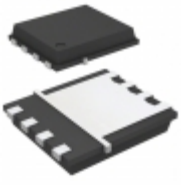
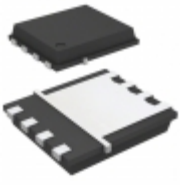



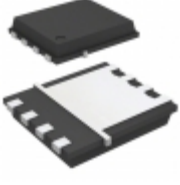
	<h2 style="color: #D9534F;">FDMS86200</h2> <p>Hersteller-Teilenummer: FDMS86200</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 150V POWER56</p> <p>Datenblätter:  FDMS86200.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 15843 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS86200
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 150V POWER56
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	15843 pcs Stock
Serie	PowerTrench®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	Power56
Verlustleistung (max)	2.5W (Ta), 104W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	150V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	9.6A (Ta), 35A (Tc)
Rds On (Max) @ Id, Vgs	18 mOhm @ 9.6A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	46nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2715pF @ 75V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































FDMS86200 ist neu im Original, Suche FDMS86200 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS86200 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMS86200: Info@Y-IC.com

Sie können auch interessiert sein:

 FDMS86182 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 78A 8PQFN	 FDMS86201 AMI Semiconductor / ON Semiconductor MOSFET N-CH 120V POWER56	 FDMS86201 Fairchild/ON Semiconductor MOSFET N-CH 120V POWER56	 FDMS86181 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 44A POWER56
 FDMS86181 Fairchild/ON Semiconductor MOSFET N-CH 100V 44A POWER56	 FDMS86200 AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V POWER56	 FDMS86183 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 51A 8PQFN	 FDMS86200DC AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 9.3A POWER 56

heiße Teile

Mehr

 FDMS8560S	 FDMS8570S	 FDMS8570S	 FDMS86101	 FDMS86101
 FDMS86101A	 FDMS86101A	 FDMS86101DC	 FDMS86101DC	 FDMS86102LZ
 FDMS86102LZ	 FDMS86103L	 FDMS86103L	 FDMS86104	 FDMS86104
 FDMS86105	 FDMS86105	 FDMS86150	 FDMS86150	 FDMS86152
 FDMS86152	 FDMS86181	 FDMS86181	 FDMS86182	 FDMS86183
 FDMS86200	 FDMS86201	 FDMS86201	 FDMS8622	 FDMS8622
 FDMS86250	 FDMS86250	 FDMS86257	 FDMS86300	 FDMS86300
 FDMS86320	 FDMS86320	 FDMS86322	 FDMS86322	 FDMS86500L
 FDMS86500L	 FDMS86520	 FDMS86520	 FDMS86520L	 FDMS86520L
 FDMS86540	 FDMS86540	 FDMS86550	 FDMS86550	 FDMS86581_085

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